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On-demand engineerable visible spectrum by fine control of electrochemical reactions

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ABSTRACT

Tunability of optical performance is one of key technology for adaptive optoelectronic applications, such as camouflage clothing, displays, and infrared shielding. High-precision spectral tunability is of great importance for some special applications with on-demand adaptability but remains challenging. Here we demonstrate a galvanostatic control strategy to achieve the goal, relying on the finding of the quantitative correlation between optical properties and electrochemical reactions within materials. An electrochromic electro-optical efficiency index is established to optically fingerprint and precisely identify electrochemical redox reactions in the electrochromic device. Consequently, the charge-transfer process during galvanostatic electrochemical reaction can be quantitatively regulated, permitting precise control over the final optical performance and on-demand adaptability of electrochromic devices as evidenced by an ultralow deviation of < 3.0%. These findings not only provide opportunities for future adaptive optoelectronic applications with strict demand on precise spectral tunability but also will promote in situ quantitative research in a wide range of spectroelectrochemistry, electrochemical energy storage, electrocatalysis, and material chemistry.

Keywords: electrochromics, fine control, spectral tunability, high precision, galvanostatic control
INTRODUCTION

Due to the inherent ability to persistently and reversibly change the optical properties, spectrum-controlling materials and devices are triggering many crucially notable optoelectronic applications, such as camouflage clothing [1,2], displays [3-7], infrared cloaking [8-10], smart windows [11-15], etc. To meet the adaptive requirements, there is a keen interest in dynamically and precisely regulating the optical features that underpins the functionality of spectrum-controlling objects. For example, the optical features of camouflage clothing and infrared shielding should be precisely and sensitively controlled to adapt to changes in the surrounding environment in real time. The optical performance and color of displays must be precisely controlled to provide high-definition image quality. The optical spectrum of smart windows should be precisely regulated according to the change under solar irradiation, so as to maintain indoor temperature. Precise and adaptive spectral tunability is therefore a highly desirable function for these spectrum-controlling related technologies [8,16-19]. Thus far, several spectrum-controlling technologies have been developed, such as electro-/thermo-/photo-/magneto-/mechano-chromic devices [20-38], biomimetic color-changing systems [39-42], which are operated through electrochemical redox reactions, phase transitions, or nano-/micro-structural changes [13,43-52]. Among them, phase transition requires relatively fixed working temperatures and suffers from the thermal hysteresis issue [8,25,53,54]. Fine control of nano-/micro-structural characteristics is extremely difficult, making it challenging to precisely regulate the optical properties of these objects [16].
Electrochemical redox reactions can be readily controlled by facile voltage-driving maneuverability to enable the dynamic spectra tunability of electrochromics [3, 55-57], making it promising spectrum-controlling technology [58-61]. Previous studies have suggested the basic spectrum-controlling mechanism of electrochromic materials. Driven by an external electric field, the simultaneous intercalation/de-intercalation of electrons and active ions (e.g., H\(^+\), Li\(^+\), Zn\(^{2+}\), Al\(^{3+}\)) into/from electrochromic materials (typically WO\(_3\)), results in the transition between chemical valences of electroactive components, which is responsible for spectral tunability [21, 58, 62-67]. However, the precise spectra tunability of electrochromics is facing three formidable challenges: i) The quantitative correlation between the electrochemical process and optical properties remains undefined. The electrochromic process for materials such as nickel oxide (NiO) [68-69], vanadium oxide [70-71], and some organic electrochromic materials [72-73], generally relates to two- or multi-step electrochemical redox reactions. The lack of an evaluation method to precisely and optically identify electrochemical redox reactions prevents the high-precision spectral tunability of electrochromic materials and devices. ii) Voltage hysteresis in the change of the optical performance during the electrochromic process causes imprecise spectral adaptability [12, 74]. iii) Electrochromic devices generally suffer from self-bleaching [75, 76] due to leakage currents or undesirable interfacial side reactions. These behaviors cause the transfer of ineffective charges within the electrochromic devices, limiting the precision of electrochemically controlled optoelectronic applications. Therefore, exploring effective ways to overcome these
bottlenecks is urgent for the precise spectral tunability of electrochromic technologies.

Herein, we demonstrate an effective methodology that enables the precise spectral tunability of electrochromic materials and devices. An electrochromic electro-optical efficiency index ($\varepsilon$) was first proposed to optically fingerprint and accurately identify different electrochemical redox reactions, and thus to quantitively bridge the electrochromic process and electrochemical reactions. On this basis, a galvanostatic control strategy is proposed to quantitatively regulate the electrochemical charge-transfer process and consequently permit precise control over the optical performance of the electrochromic device with an ultralow deviation of < 3.0%. We believe that these findings will pave the way for the precise and adaptive spectral tunability of spectrum-controlling technologies, and provide in situ quantitative insights into electrochemical behaviors of electrochemical energy storage, electrocatalysis, material chemistry, etc.

RESULTS AND DISCUSSION

Fundamentals of electrochromic electro-optical efficiency

Coloration efficiency ($CE$) is a commonly used parameter for quantitatively evaluating the optical-changing capability of electrochromic materials and devices, but it cannot distinguish different electrochemical reactions occurring in a material. It is defined as the change in optical density ($\Delta OD$) per unit of inserted charge ($\Delta Q$) into
electrochromic materials switching from a bleached state to a colored state \((CE = \Delta OD/\Delta Q)\) [77-79]. The Beer–Lambert law suggests that the optical density (or optical absorbance) is proportional to the optical absorption coefficient \((\alpha)\) and the concentration of the absorptive species \((c)\). Thus, the optical density of electrochromic materials strongly depends on the optical band gap according to Tauc's relation between \(\alpha\) and optical band gap \((E_g)\): 
\[
\alpha h\nu = B(h\nu - E_g)^m
\]
where \(h\) and \(\nu\) are respectively the Planck constant and the frequency of the incident photon, \(B\) is a constant, and \(m\) is an index referring to the type of semiconducting material and the direct/indirect transition [80].

Accordingly, we propose an electrochromic electro-optical efficiency \((\varepsilon)\) as a quantitative evaluation index to optically identify each electrochemical redox reaction occurring in electrochromic materials. Combining the coloration efficiency and the Beer–Lambert law, \(\varepsilon\) can be obtained from (Figure 1a, a detailed description can be obtained in Sec. 2 of Supplementary Information):

\[
\varepsilon = \Delta \alpha L/nF
\]

where \(\Delta \alpha\) represents the difference in the optical absorption coefficient of the electrochromic material before and after the electrochemical reaction, and \(n\) is the number of transferred charges contributing to the formation of one absorptive species. \(L\) and \(F\) represent the thickness of the electrochromic layer and the Faraday constant, respectively. Clearly, for a specific electrochemical reaction, the \(\varepsilon\) at a specific wavelength is directly proportional to the \(\Delta \alpha\) that is only decided by the change of \(E_g\)
before and after the electrochromic operation. Thus, \( \varepsilon \) reflects the change in the optical band gap of the material induced by the electrochemical reaction and can serve as a tool to identify the electrochromic capability of a material, which lays the foundation for \textit{in situ} quantitatively elucidating and manipulating the electrochemical redox process of materials. For an electrochromic material with a stable structure and a fixed thickness, the \( \varepsilon \) is theoretically a constant during the electrochromic process with a certain electrochemical redox reaction. When the electrochromic process involves a two- or multi-step electrochemical redox process, there are two or several \( \varepsilon \) values during the whole electrochromic process. Although \( \varepsilon \) is no longer a constant, it should be the same during a particular electrochemical step. At a specific time \((t)\), the \( \varepsilon_t \) can be derived from:

\[
\varepsilon_t = \lim_{\Delta t \to 0} \frac{OD_{\Delta t}}{Q_{\Delta t}} = \frac{\lim_{\Delta t \to 0} OD_{\Delta t}}{\lim_{\Delta t \to 0} Q_{\Delta t}} = \frac{OD'_t}{I_t} \tag{2}
\]

where \( OD'_t \) and \( I_t \) are the first-order derivative of \( OD \) and the corresponding current density at \( t \), respectively. \( \Delta OD_{\Delta t} \) and \( \Delta Q_{\Delta t} \) separately represent the changes in optical density and the effectively transferred charges over a period \((\Delta t)\). Accordingly, we can obtain the \( \varepsilon_i \) values at different steps of the electrochemical redox process, and quantitatively identify every electrochemical redox reaction occurring in an electrochromic material at a given \( \lambda \). As a result, the optical density can be controlled as follows:

\[
OD = OD_0 + \sum_{i=1}^{N} \varepsilon_i Q_i = OD_0 + \sum_{i=1}^{N} \varepsilon_i (\int I_t \, dt) \tag{3}
\]

where \( OD_0 \) is the original optical density. \( \varepsilon_i \) and \( Q_i \) represent the electrochromic
electro-optical efficiency and the transferred effective charges in the process of the \( i^{th} \) electrochemical redox reaction, respectively, and \( N \) refers to the total number of reversible electrochemical redox reactions occurring in the electrochromic process. When a constant \( I_t \) is maintained under galvanostatic control, the optical density of the electrochromic objects can be precisely and facilely tuned by controlling the operation time to regulate the effectively transferred charges.

**Precise spectral tunability of electrochromic materials**

WO\(_3\) is a typical cathodic-colored electrochromic material with a one-step electrochemical redox process. Thus, we first choose amorphous WO\(_3\) (detailed structural and chemical information is presented in Sec. 3.1 of Supplementary Information, Figures S1-S4) as a proof-of-concept sample to validate the feasibility of precisely tuning the optical performance. Figure 1b shows a typical cyclic voltammogram (CV) profile of the WO\(_3\) sample at a sweep rate of 0.05 V/s in the potential range of −1.0 to 1.0 V (vs. Ag/AgCl). One cathodic peak was observed at 0.095 V with the absence of obvious anodic peaks, indicating a one-step electrochemical redox process of the WO\(_3\). To get further insight into the electrochromic mechanism of WO\(_3\) thin film, we analyze the change in the chemical composition of the sample at colored and bleached states, followed by the switching of the step potential between −1.0 and 1.0 V (vs. Ag/AgCl). As shown in Figure S5, the sample presents a broad spectral modulation range from 15.9% to 89.8% at 550 nm. The high-resolution W 4f XPS spectrum of the original state can be deconvoluted into two pairs of characteristic peaks, respectively corresponding to W 4f\(_{5/2}\) and W
4f$_{7/2}$ of the dominant W$^{6+}$ at 37.5 and 35.5 eV and that of the minor W$^{5+}$ at 37.1 and 34.9 eV (Figure 1c). Compared with the original state, the intensity ratio of the W$^{5+}$ to W$^{6+}$ peaks at the colored state increases, implying the transition from W$^{6+}$ to W$^{5+}$ during the coloring process. When we switched the sample from the colored state to the bleached state, the significantly reduced W$^{5+}$ peak intensity signifies the oxidation of W$^{5+}$ to W$^{6+}$ [81-82]. Density functional theory (DFT) calculations were performed to analyze the charge transfer and density of states (DOS) distribution in the bleached and colored states. For the bleached state without the intercalation of Li$^{+}$ into the WO$_3$ lattice, the band gap is 1.171 eV (Figure S6). In the colored state, Li-ions and electrons are co-intercalated into the WO$_3$ lattice, and the reduced and increased charge densities (yellow) around the W and Li atoms can be clearly observed in the charge density difference, which implies the conversion from W$^{6+}$ to W$^{5+}$. The corresponding band gap is decreased to 0 eV.

In situ optical monitoring was implemented to analyze the electrochemical redox reaction of the WO$_3$ sample. Figure 1b shows that the optical transmittance at 550 nm synchronously changes with the proceeding of a typical CV profile, presenting a typical voltage hysteresis behavior. The accumulated area capacity and the corresponding optical density during the cyclic voltammetry measurement are calculated accordingly. As shown in Figure 1d, with the scanning of potential, evolution of optical density demonstrates the same tendency as that of area capacity. Meanwhile, leakage current through the sample tends to be zero and correspondingly the optical density remains constant when the potential is larger than 0.3 V. A linear
correlation between the optical density and the area capacity is plotted and fitted in Figure 1e, indicating that the electrochromic process of the WO$_3$ thin film has a constant $\varepsilon$ of 34.3 \pm 0.1$ cm$^2$/C, and a one-step electrochemical redox process dominates the electrochromic behavior of the WO$_3$ layer.

To demonstrate the feasibility of precisely tuning the optical properties by quantitatively regulating the effectively transferred charges, the evolution of optical transmittance at 550 nm was in situ monitored during electrochemical operation. Derived from Eq. 1, the change in optical density is proportional to the transferred capacity. WO$_3$ is usually chosen as an anode material in electrochromic energy storage devices. According to Eq. 3, galvanostatic control was proposed to quantitatively regulate the transferred capacity and consequently on-demand tune the optical density. Figures 2 and S7 show the evolution of the in situ optical transmittance of the WO$_3$ layer, separately operated under galvanostatic control and routine voltage control. As observed in Figure 2a, for galvanostatic control, the evolution of the optical transmittance shows a clear progression, which accompanies the insertion/extraction of the effective capacity into/from electrochromic WO$_3$, with a symmetric process of charge and discharge. Figure 2b shows a 2D contour of the optical transmittance plotted against the evolution of the capacity. The WO$_3$ film presents a continuous change in optical transmittance and coloration. In the subsequent extraction of capacity from the WO$_3$ layer, a reverse and symmetric contour of the reversible bleaching process was observed for the evolution of optical transmittance. Moreover, optical photos with the same capacity retention shared a
similar color between the charge (bleaching) and discharge (coloring) processes. Such phenomena indicate the effective maneuverability in the quantitative control over the optical transmittance of electrochromic materials through galvanostatic control. These results also suggest a robust and direct relationship between the optical properties and the transferred capacity during the galvanostatic-control electrochromic process.

As observed from the 3D colormap and the 2D contour of the optical transmittance, based on voltage-controlled operation in the range of 1.0 V to -1.0 V, there is no obvious variation until 0.0 V, at which a sharp decrement starts (Figure S7). Moreover, the minimum optical transmittance is not achieved at the lowest potential of -1.0 V, and the full transparent state is obtained at 0.5 V rather than at 1.0 V when the operating potential is increased (Figure S7a). In addition, optical photos at the same operating potentials show a clear difference in colors during the increasing and decreasing potential processes (Figure S7b), attributing to the obvious voltage hysteresis effect of the voltage-controlled electrochromics. Although the sweep rates of the reductive and oxidative processes of a typical WO$_3$ sample share the same value of 0.05 mV/s, the evolution of optical transmittance differs. Thus, there is no direct quantitative relationship between the optical properties and operating potential of WO$_3$.

Figure S8a presents the galvanostatic charge-discharge (bleaching-coloring) profiles at an area current of 0.5 mA/cm$^2$ and the galvanostatically controlled evolution of optical transmittance at 550 nm. Galvanostatic discharge followed by
lowering the working potential boosts the intercalation of Li\(^+\) into the WO\(_3\) lattice, synchronously establishing the coloring process, while the galvanostatic charge process corresponds to bleaching behavior. Under the careful implementation of galvanostatic control, when the accumulated capacity is accurately regulated against time, the optical density of the WO\(_3\) sample is tuned linearly (Figure S8b). The acquired experimental values of the optical density under galvanostatic control are extremely close to the theoretical data calculated with Eq. 3 (Figure 2c). The linearly fitted \(\varepsilon\) value is \(34.5 \pm 0.1\) cm\(^2\)/C (Figure S9), an approximation to that obtained by the CV test. Compared with the \(\varepsilon\) value obtained by the CV test, the optical density obtained through galvanostatic control only shows a low deviation of 0.3%. In addition, when the area current under galvanostatic control was adjusted to 0.2 mA/cm\(^2\), the optical density of WO\(_3\) can also be precisely tuned as the transferred capacity is quantitatively regulated (Figure S10). These results confirm the feasibility of quantitatively galvanostatic control over the optical properties of electrochromic materials with a one-step electrochemical redox process.

NiO was used as a proof-of-concept electrochromic material with a reversible two-step electrochemical redox process (See Sec. 3.2 of Supplementary Information, Figures S11-S17), as it is a typical anodic-colored material complementary to cathodic-colored WO\(_3\). DFT calculation in Figure 3a suggests that the formation of Ni\(^{3+}\) and Ni\(^{4+}\) on the surface of NiO during the desorption of Li-ions separately occur at the potential plateaux of 3.1 and 3.8 V (vs. Li/Li\(^+\)), which provides cogent evidence for the two-step electrochemical redox process. Figure 3b shows the \textit{in situ} monitored
optical transmittance of the NiO$_{1.27}$ sample during the CV tests, where the oxygen number was determined by Ni$^{3+}$/Ni$^{2+}$ atomic ratio of the deconvoluted Ni 2p$_{3/2}$ peak in the XPS result of the pristine sample [83-84]. The optical transmittance-voltage correspondence is also hysteretic. Changes in optical density and area capacity during the CV tests are presented in Figure S18. Unlike WO$_3$ with a one-step electrochemical redox process (Figure 1b), the NiO$_{1.27}$ sample presents a non-negligible deviation in the evolution of the optical density from the development of the area capacity as two electrochemical redox reactions coexist.

According to Eq. 2, at different electrochemical redox steps, the first-order derivative of the optical density is proportional to the area current. Figure 3c shows the first-order derivative curve of the optical density and the corresponding CV profile. Similar shapes of both curves verify the strong correlation between the optical density and the electrochemical redox reaction. Both curves show partial overlap (Figures 3c and S19). Considering the complexity of fitting the derivative plot of the optical density against the area current due to the existence of the same current at different potentials, we linearly fitted the corresponding optical density versus the area capacity at different electrochemical redox stages (Figure 3d). For the first pair of electrochemical redox peaks at 0.475/0.155 V (vs. Ag/AgCl), $\varepsilon$ is fitted to be 36.5 ± 0.2 cm$^2$/C; for another pair of peaks at 1.055/0.735 V (vs. Ag/AgCl), the $\varepsilon$ is estimated to be 30.2 ± 0.2 cm$^2$/C. The difference in $\varepsilon$ confirms the occurrence of two electrochemical redox reactions in the electrochromic process of the NiO$_{1.27}$ sample within the range of -0.5 to 1.5 V vs. Ag/AgCl. No capacity hysteresis was observed.
during the CV test for NiO\textsubscript{1.27}, even though potential hysteresis was observed for both pairs of electrochemical redox peaks.

NiO is a typical cathode material for electrochromic energy storage devices. Galvanostatic control in the potential range of -0.5 to 1.5 V vs. Ag/AgCl was also implemented for the adaptive optical modulation of the NiO\textsubscript{1.27} sample. Figure S20a-b shows the galvanostatic charge-discharge profiles, the real-time optical transmittance at 550 nm, and the optical photos of NiO\textsubscript{1.27} under the galvanostatic control at 0.3 mA/cm\textsuperscript{2}. The galvanostatic discharge process can continuously increase the optical transmittance from 34% to 91%, while the galvanostatic charge process corresponds to the coloring process. Under the galvanostatic control, the optical density at 550 nm is linearly tuned by regulating the area capacity (Figure S20c). Notably, no capacity hysteresis is observed in the change of the optical density of the NiO\textsubscript{1.27} sample. The experimental result of galvanostatically controlled optical density nearly overlaps the theoretical data calculated from Eq. 3 (Figure S20d). Due to the occurrence of two electrochemical redox reactions, the plot of the optical density against the area capacity comprises two steps. Both steps have \( \varepsilon \) of 36.2 \( \pm \) 0.1 and 30.5 \( \pm \) 0.1 cm\textsuperscript{2}/C (Figure S20e), which are approximately equal to the results obtained in the CV tests. At different stages, \( \varepsilon \) has a small deviation of ca. 0.8%, indicating the excellent feasibility of precisely tuning the optical properties of electrochromic materials with a two-step electrochemical redox process. Moreover, different currents are applied to confirm the validity of the galvanostatic control strategy for precise and adaptive optical modulation of the electrochromic materials. The galvanostatic control is also
suitable for precisely tuning the optical performance with negligible deviation at 0.2 mA/cm² (Figure S21). Similarly, the electrochromic material (typically LiMn₂O₄) with a multi-step electrochemical redox process can be galvanostatically controlled to realize precise spectral tunability (See Sec. 3.3 in Supplementary Information, Figures S22-S23).

Precise spectral tunability of electrochromic device

An electrochromic device with WO₃ anode and NiO₁.₂₇ cathode (more detailed information can be obtained in Sec. 3.4 of Supplementary Information, Figures S24-S28) was assembled to further demonstrate the validity of precise spectral tunability. To eliminate the influence of ineffective charges induced by possible side reactions between ion-conducting layer (e.g., liquid, gel, solid polymer electrolyte) and electrochromic layers, we constructed an all-solid-state inorganic electrochromic energy storage device (AEESD). The configuration of the device is schematically shown in Figure 4a, where the electrochemical process corresponds to the shuttle of charges (Li-ions and electrons) between the anode and the cathode. The charge (coloring) process relates to the simultaneous occurrence of the oxidation of low-valence Ni species and the reduction of W⁶⁺ species, while the discharge (bleaching) process is converse. Thus, the ε of the device is theoretically contributed by a combined effect of synchronous electrochemical reactions of the anode and the cathode during the electrochromic process. In addition, we introduced electron-blocking tantalum oxide (Ta₂O₅) buffer layers within the AEESD to limit leakage current (Figures 4b-c).
When driven by the operating step voltage switched between -1.5 V and 2.0 V, the AEESD has a tunable range of optical transmittance from 4.0% to 66.5% at 550 nm (Figure S29c). Figure S29d shows the typical galvanostatic charge-discharge profiles of the AEESD at different volumetric currents. At 1.0 A/cm$^3$, a good cycling stability with negligible electrochromic degradation after 1000 cycles (Figure S30). Figure S31a shows the optical memory effect of the AEESD under the condition of an open circuit. Clearly, the AEESD can stably maintain the colored state without obvious self-bleaching effect even after 30 min. The corresponding open-circuit voltage can be maintained at about 1.5 V for 15 min (Figure S31b). In contrast, once the open circuit is conducted, the electrochromic device without the electron-blocking Ta$_2$O$_5$ buffer layer shows rapid self-bleaching behavior and obvious leakage current, with the optical transmittance in the colored state quickly increasing from 11.7 % to 61.7 % within 5 min (Figures S31c and S32). Correspondingly, the open-circuit voltage rapidly drops to 0 V in 2 min (Figure S31d). Thus, the embedment of electron-blocking Ta$_2$O$_5$ layers effectively eliminates the influence of the leakage current flowing within the AEESD.

Figure S33a shows the electrochromic performance of the AEESD tested via voltage-step chronoamperometry. The optical transmittance of the AEESD in the colored or bleached states becomes stable when the corresponding area current approaches zero. There is no distinct difference in the peak currents between the coloring and bleaching processes, signifying the voltage balance during the electrochromic process. Further, the accumulated area capacity and the optical density
share the same tendency during testing process, implying their close interplay (Figure S33b). Figure S34a presents a typical CV profile of the AEESD and the *in situ* optical transmittance at 550 nm. Electrochemical redox peaks are observed in the CV profile, with the coloring and bleaching behaviors occurring in the cathodic and anodic scanning processes, respectively. A constant optical transmittance is present when the area current approximates zero in the voltage range of -0.5 to -1.5 V. This implies the absence of a leakage current, which is consistent with the results mentioned above. Figure S34b shows similar evolution profiles of the accumulated area capacity and the optical density of the AEESD during CV tests. The first-order derivative of the optical density is plotted against time, presenting a similar relationship as that with the area current (Figure 4d). The changes in the optical density and the area current follow Eq. 2, demonstrating the validity of precisely manipulating the optical properties of ASSED. Figure S35 presents a linear fitting of the optical density against the area capacity at two electrochemical steps for the AEESD. The electrochemical steps are determined by the electrochemical redox peaks in the CV profiles. For the first and second steps, \( \varepsilon \) are fitted to be 70.4 ± 0.3 and 63.5 ± 0.2 cm\(^2\)/C, respectively, which coincide with the synchronous electrochemical redox reactions of the WO\(_3\) anode and the NiO\(_{1.27}\) cathode.

Furthermore, galvanostatic control was used to modulate the optical property of the AEESD. Figure S36a displays the galvanostatic charge-discharge profiles at 1.0 A/cm\(^3\) and the real-time modulation of the optical transmittance at 550 nm under galvanostatic control. The charge and discharge processes respectively correspond to
the coloring and bleaching processes with a wide optical modulation range of 3.5% to 64.4%. Under galvanostatic control, the optical density of the AEESD presents proportional correlation with the area capacity (Figure S36b). Consequently, the optical density can be precisely tuned as the area capacity is accurately regulated, which extremely approximates the data obtained by theoretical calculation (Figure 4e). The fitted \( \varepsilon \) values are 72.5 ± 0.2 and 62.1 ± 0.1 cm\(^2\)/C for two different electrochemical steps in the galvanostatic control of the AEESD, which approximate the results obtained in the CV test (Figure S37). The small deviation of below 3.0 % demonstrates the reliable maneuverability in the precise spectral tunability of the electrochemical energy storage device. Thus, the optical properties of the AEESD can be precisely tuned through galvanostatic control to provide on-demand adaptability for the background environment.

**CONCLUSIONS**

In summary, we have electrochemically and quantitatively realized the precise spectral tunability of electrochromic materials and devices. An index of electrochromic electro-optical efficiency has been deduced to optically fingerprint and accurately identify different electrochemical redox reactions for electrochromic materials at a given wavelength. By identifying optical fingerprints, this index can quantitatively bridge the electrochemical processes and optical performance, which will boost *in situ* quantitative studies on elucidating and manipulating electrochemical...
behaviors of materials, and lay the theoretical foundation for precisely tunable electrochromic performance. Based on the linear correlation between optical performance and electrochemical process established with the index, a galvanostatic control strategy has been proposed to realize the precise and adaptive spectral tunability of electrochromic materials and devices. Galvanostatic control not only realizes hysteresis-free maneuverability but also breaks through the limitations of low-precision spectral tunability and enables the on-demand control of the optical performance. We believe that this work will shed light on the precise and adaptive spectral tunability of spectrum-controlling technologies for optoelectronic applications including visible and infrared camouflage, displays, and visual microelectronic devices.

METHODS

Preparation of electrochromic materials

The WO$_3$, NiO$_{1.27}$ and LiMn$_2$O$_4$ layers were deposited on glass substrates coated with indium tin oxide (ITO) or fluorine-doped tin oxide (FTO) by the reactive direct-current magnetron sputtering method. More details on deposition parameters of both electrochromic materials are presented in Table S1. The as-deposited LiMn$_2$O$_4$ layer was placed into a tube furnace and heated at 600 °C in high-purity Ar/H$_2$ for 6 h.

Fabrication of electrochromic devices

The all-solid-state electrochromic energy storage devices were respectively prepared
on the ITO-coated glass substrates layer by using magnetron sputtering at room temperature, as shown in our previous work [85]. More details on deposition parameters of both devices are presented in Table S1. For the characterization of optical transmittance of single Ta$_2$O$_5$ and LiNbO$_3$ layers, both were deposited on glass substrates, respectively. Besides, Au thin film, LiNbO$_3$ layer, and 2$^{nd}$ Au thin film were successively prepared on a glass substrate (Glass/Au/LiNbO$_3$/Au) for the measurement of electrochemical impedance spectroscopy (EIS) of LiNbO$_3$ layer [85].

**Electrochemical and optical measurements**

Cyclic voltammetry and galvanostatic-controlled charge-discharge measurement of electrochromic materials was carried out in a three-electrode electrochemical cell (Figure S38) using a CHI 660E electrochemical workstation. The electrochromic material, Ag/AgCl and Pt foil serving as working electrode, reference electrode, and counter electrode, respectively, were immersed in an electrolyte of lithium perchlorate (1 M LiClO$_4$) dissolving in propylene carbonate (PC) solvent. *In situ* monitoring optical transmittance at 550 nm versus time was acquired in the process of electrochemical testing. The optical transmittance spectra of the devices were acquired by the UV-Vis-NIR spectrophotometer. Galvanostatic-controlled charge-discharge processes were implemented by a battery test system.

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AUTHOR CONTRIBUTIONS

The project was initiated by Q.L., Y.T., and X.D., and coordinated by H.-M.C. Y.T., Q.L., X.D. and H.-M.C. conceived and designed the experiments and calculations. Q.L., L.L. and M.L. fabricated the samples, conducted the chemical and structural characterization, electrochemical and optical experiments. Y.Z. conducted the theoretical calculation work. Y.T., X.D., Q.L., L.L. and B.D. co-wrote the paper. All authors discussed the results and commented on the manuscript.

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Figure 1. Analysis of the electrochromic mechanism of WO$_3$ with a one-step electrochemical process. (a) Schematic illustration of theoretical analysis on the electrochromic electro-optical efficiency. (b) Typical CV profile and *in situ* monitored optical transmittance at 550 nm. (c) High-resolution W 4f XPS spectra of the WO$_3$ sample at different states. (d) Changes in the area capacity and the optical density and (e) linearly fitted $\varepsilon$ during the CV test.
**Figure 2.** Precise spectral tunability of electrochromic WO$_3$ material under galvanostatic control. (a) 3D colormap of the *in situ* optical transmittance and the corresponding 2D projection of a typical WO$_3$ electrochemical material operating under galvanostatic control (galvanostatic charge-discharge) at 0.5 mA/cm$^2$. (b) Measured 2D contour of the *in situ* optical transmittance plotted against the evolution of the inserted area capacity and the corresponding optical photos at different area capacities under galvanostatic control. (c) Galvanostatic control over the optical properties of WO$_3$: comparison of optical density obtained from between theoretical calculation and galvanostatic control.
Figure 3. Mechanism analysis and ε evaluation of NiO$_{1.27}$ with a two-step electrochemical process. (a) Theoretically calculated redox potential for the formation of high-valence nickel accompanied by the adsorption/desorption of Li$^+$ ions. (b) Typical CV profile and in situ monitored optical transmittance at 550 nm and (c) the real-time derivative of the optical density during the CV test. (d) Linearly fitted ε values during the CV tests at different electrochemical redox steps.
Figure 4. Precise spectral tunability of the AEESD. (a) Schemes of configuration, (b) cross-section SEM image, and (c) EDX elemental mapping of the AEESD. (d) Real-time derivative of the optical density accompanied with the proceeding CV tests. (e) Galvanostatic control of optical density at 550 nm and its comparison with that obtained from theoretical calculation with Eq. 3.